

2.5-V 460-kbps RS-232 TRANSCEIVER WITH ±15-kV ESD PROTECTION

Check for Samples: TRS3318E

FEATURES

- ESD Protection for RS-232 I/O Pins
 - ±15 kV (Human-Body Model)
 - ±8 kV (IEC 61000-4-2, Contact Discharge)
 - ±15 kV (IEC 61000-4-2, Air-Gap Discharge)
- 300-μA Operating Supply Current
- 1-μA Low-Power Standby Mode (With Receivers Active)
- Designed to Transmit at a Data Rate of 460 kbps
- Auto-Powerdown Plus Option Features Flexible Power-Saving Mode
- Operates From a Single 2.25-V to 3-V V_{CC} Supply
- Designed to be Interchangeable With Industry Standard '3318 Devices

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Cellular Phones
- Notebooks
- Hand-Held Equipment
- Pagers

DESCRIPTION

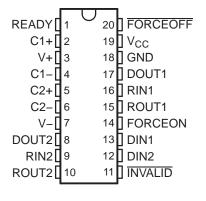
The TRS3318E is a dual-driver, dual-receiver, RS-232-compatible transceiver. The device features auto-powerdown plus and enhanced electrostatic discharge (ESD) protection integrated into the chip. Driver output and receiver input are protected to ±15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ±8 kV using the IEC 61000-4-2 Contact Discharge method, and ±15 kV using the Human-Body Model (HBM).

The device operates at a data rate of 460 kbps. The transceiver has a proprietary low-dropout driver output stage, enabling RS-232-compatible operation from a 2.25-V to 3-V supply with a dual charge pump. The charge pump requires only four 0.1-µF capacitors and features a logic-level output (READY) that asserts when the charge pump is regulating and the device is ready to begin transmitting.

The TRS3318E achieves a 1-µA supply current using the auto-powerdown feature. This device automatically enters a low-power power-down mode when the RS-232 cable is disconnected or the drivers of the connected peripherals are inactive for more than 30 s. The device turns on again when it senses a valid transition at any driver or receiver input. Autopowerdown saves power without changes to the existing BIOS or operating system.

This device is available in two space-saving packages: 20-pin SSOP and 20-pin TSSOP.

DB OR PW PACKAGE (TOP VIEW)



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DETAILED DESCRIPTION

Flexible control options for power management are featured when the <u>serial port and</u> driver inputs are inactive. The auto-powerdown plus feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense valid signal transitions on all receiver and driver inputs for approximately 30 s, the built-in charge pump and drivers are powered down, reducing the supply current to 1 μ A. By disconnecting the <u>serial port</u> or placing the peripheral drivers off, auto-powerdown plus can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown <u>plus enabled</u>, the device activates automatically when a valid signal is applied to any receiver or driver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μ s (typical number). INVALID is low (invalid data) if all receiver input voltage are between -0.3 V and 0.3 V for more than 30 μ s (typical number).

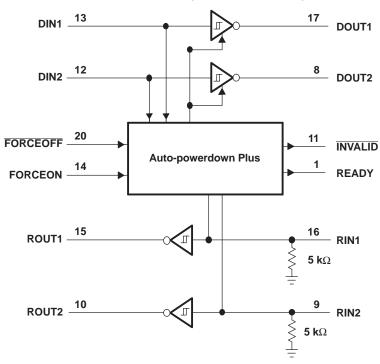
FUNCTION TABLE(1)

	INPUT CO	ONDITIONS			OUTPUT	STATES		
FORCEON	FORCEOFF	RECEIVER OR DRIVER EDGE WITHIN 30 s	VALID RS-232 LEVEL PRESENT AT RECEIVER	DRIVER	RECEIVER	INVALID	READY	OPERATING MODE
	*	*	Auto-Powerd	own Plus Co	nditions		•	
Н	Н	No	No	Active	Active	L	Н	Normal operation, auto-powerdown plus disabled
Н	Н	No	Yes	Active	Active	Н	Н	Normal operation, auto-powerdown plus disabled
L	Н	Yes	No	Active	Active	L	Н	Normal operation, auto-powerdown plus enabled
L	Н	Yes	Yes	Active	Active	Н	Н	Normal operation, auto-powerdown plus enabled
L	н	No	No	Z	Active	L	L	Power down, auto-powerdown plus enabled
L	Н	No	Yes	Z	Active	Н	L	Power down, auto-powerdown plus enabled
X	L	X	No	Z	Active	L	L	Manual power down
Х	L	X	Yes	Z	Active	Н	L	Manual power down
			Auto-Powe	erdown Cond	itions			
ĪNVALID	INVALID	х	No	Z	Active	L	L	Power down, auto-powerdown enabled
ĪNVALID	ĪNVALID	Х	Yes	Active	Active	Н	Н	Normal operation, auto-powerdown enabled

(1) H = high level, L = low level, X = irrelevant, Z = high impedance



LOGIC DIAGRAM (POSITIVE LOGIC)



TERMINAL FUNCTIONS

TERMII	NAL	DECORIDEION
NAME	NO.	DESCRIPTION
C1+	2	Positive voltage-doubler charge-pump capacitor
C1-	4	Negative voltage-doubler charge-pump capacitor
C2+	5	Positive inverting charge-pump capacitor
C2-	6	Negative inverting charge-pump capacitor
DIN	12, 13	CMOS driver inputs
DOUT	8, 17	RS-232 driver outputs
FORCEOFF	20	Force-off input, active low. Drive low to power down transmitters and charge pump. This overrides auto-powerdown and FORCEON (see Function Table).
FORCEON	14	Force-on input, active high. Drive high to override auto-powerdown, keeping transmitters on (FORCEOFF must be high) (see Function Table).
GND	18	Ground
INVALID	11	Valid signal detector output, active low. A logic high indicates that a valid RS-232 level is present on a receiver input.
READY	1	Ready to transmit output, active high. READY is enabled high when V– goes below –3.5 V and the device is ready to transmit.
RIN	9, 16	RS-232 receiver inputs
ROUT	10, 15	CMOS receiver outputs
V+	3	2 × V _{CC} generated by the charge pump
V-	7	−2 × V _{CC} generated by the charge pump
V _{CC}	19	2.25-V to 3-V single-supply voltage



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC} to GND		-0.3	6	V
V+ to GND ⁽²⁾		-0.3	7	V
V- to GND ⁽²⁾		-7	0.3	٧
V+ + IV-I ⁽²⁾			13	٧
land to also a	DIN, FORCEON, FORCEOFF to GND	-0.3	6	\/
Input voltage	RIN to GND		±25	V
Output voltage	DOUT to GND		±13.2	V
Output voltage	ROUT, INVALID, READY to GND	-0.3	$V_{CC} + 0.3$	V
Short-circuit duration	DOUT to GND		Continuous	
Ocation and discinction (T. 7000)	20-pin SSOP (derate 8 mW/°C above 70°C)		640	\\
Continuous power dissipation (T _A = 70°C)	20-pin TSSOP (derate 7 mW/°C above 70°C)		559	mW
Storage temperature range		-65	150	ô
Lead temperature (soldering, 10 s)			300	ô

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

See Figure 4

	i igaio i						
				MIN	NOM	MAX	UNIT
	Supply voltage			2.25	2.5	3	٧
V _{IH}	Driver and control high-level input voltage	DIN, FORCEOFF, FORCEON	V _{CC} = 2.5 V to 3 V	0.7 × V _{CC}		5.5	V
V_{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON	V _{CC} = 2.5 V to 3 V	0		0.3 × V _{CC}	V
V_{I}	Receiver input voltage			-25		25	٧
_	Operating free six temperature	TRS3318EC		0		70	°C
IA	Operating free-air temperature	TRS3318EI		-40		85	

⁽²⁾ V+ and V- can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V.



Supply Current Section

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature, V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 μ F, T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT	
DC Characteristics (V _{CC} = 2.5 V, T _A = 25°C)						
Auto-powerdown plus supply current	FORCEON = GND, FORCEOFF = V _{CC} , All RIN and DIN idle		1	10	μΑ	
Auto-powerdown supply current	FORCEOFF = GND		1	10	μΑ	
Supply current	FORCEON = FORCEOFF = V _{CC} , No load		0.3	2	mA	

⁽¹⁾ Typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	НВМ	±15	
RIN, DOUT	IEC 61000-4-2 Air-Gap Discharge method	±15	kV
,	IEC 61000-4-2 Contact Discharge method	±8	



Driver Section

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

 $V_{CC} = 2.25 \text{ V}$ to 3 V, C1–C4 = 0.1 μ F, $T_A = T_{MIN}$ to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
Driver input hysteresis			0.3		V
Input leakage current	FORCEON, DIN, FORCEOFF		±0.01	±1	μΑ
Output voltage swing	All driver outputs loaded with 3 $k\Omega$ to ground	±3.7	±4		V
Output resistance	$V_{CC} = 0$, Driver output = $\pm 2 \text{ V}$	300	10M		Ω
Output short-circuit current ⁽²⁾			±25	±60	mA
Output leakage current	V _{CC} = 0 or 2.25 V to 3 V, V _{OUT} = ±12 V, Drivers disabled			±25	μΑ

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

 V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 μ F, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 1)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
	Maximum data rate	$R_L = 3 \text{ k}\Omega$, $C_L = 1000 \text{ pF}$, One transmitter switching	460			kbps
$ t_{PHL} - t_{PLH} $	Driver skew ⁽²⁾			100		ns
	Transition-region slew rate	$\begin{split} &V_{CC}=2.5~V,~T_A=25^{\circ}C,~R_L=3~k\Omega~to~7~k\Omega,\\ &Measured~from~3~V~to~-3~V~or~-3~V~to~3~V,\\ &C_L=150~pF~to~2500~pF \end{split}$	4		30	V/µs

Product Folder Links: TRS3318E

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C. (2) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

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Typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.



Receiver Section

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

 V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 μ F, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
Input voltage range		-25		25	V
Input threshold low	T _A = 25°C			$0.3 \times V_{CC}$	٧
Input threshold high	$T_A = 25$ °C	0.7 × V _{CC}			٧
Input hysteresis			0.3		٧
Input resistance	$T_A = 25$ °C	3	5	7	kΩ
Output leakage current			±0.05	±10	μΑ
Output voltage low	I _{OUT} = 0.5 mA			0.1 × V _{CC}	٧
Output voltage high	$I_{OUT} = -0.5 \text{ mA}$	0.9 × V _{CC}			V

⁽¹⁾ Typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

 V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 μ F (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDITIONS	TYP ⁽¹⁾	UNIT
t _{PHL}	Desair an area a retion delay.	DIN to DOUT O 150 of	0.175	
t _{PLH}	Receiver propagation delay	RIN to ROUT, C _L = 150 pF	0.175	μs
t _{PHL} - t _{PLH}	Receiver skew ⁽²⁾		50	ns

⁽¹⁾ Typical values are at V_{CC} = 2.5 V, T_A = 25°C. (2) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.



Auto-Powerdown Plus Section

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

 $V_{CC} = 2.25 \text{ V}$ to 3 V, C1–C4 = 0.1 μ F, $T_A = T_{MIN}$ to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Descrives input threshold to INIVALID high	Positive threshold		2.7	V
Receiver input threshold to INVALID high	Negative threshold	-2.7		V
Receiver input threshold INVALID low		-0.3	0.3	V
INVALID, READY voltage low	I _{OUT} = 0.5 mA		0.1 × V _{CC}	V
INVALID, READY voltage high	$I_{OUT} = -0.5 \text{ mA}$	0.8 × V _{CC}		V

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

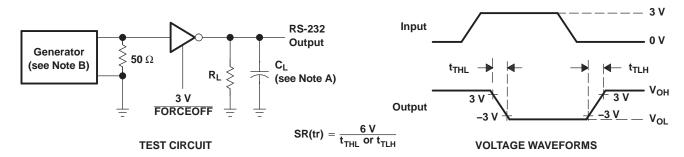
 V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 μ F, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{INVH}	Receiver positive or negative threshold to INVALID high	V _{CC} = 2.5 V		1		μs
t _{INVL}	Receiver positive or negative threshold to INVALID low	V _{CC} = 2.5 V		30		μs
t _{WU}	Receiver or driver edge to driver enabled	V _{CC} = 2.5 V		100		μs
t _{AUTOPRDN}	Receiver or driver edge to driver shutdown	V _{CC} = 2.5 V	15	30	60	s

(1) Typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

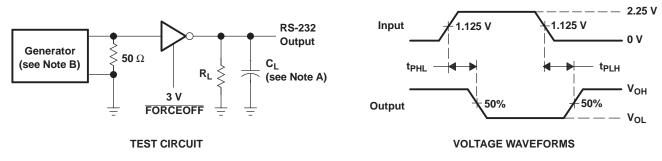


PARAMETER MEASUREMENT INFORMATION



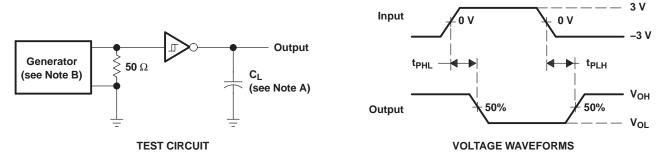
- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

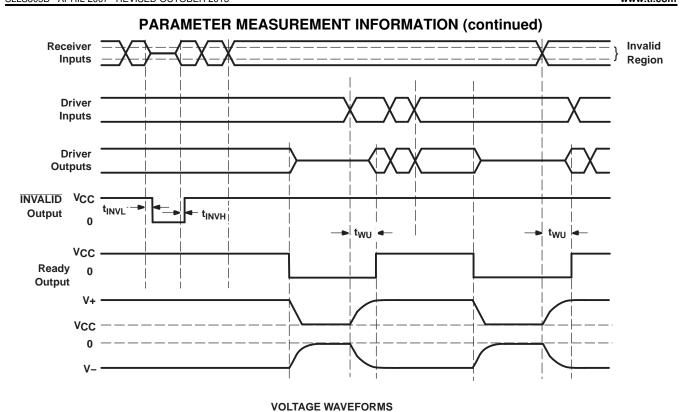
Figure 2. Driver Pulse Skew



- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le$ 10 ns, $t_f \le$ 10 ns.

Figure 3. Receiver Propagation Delay Times





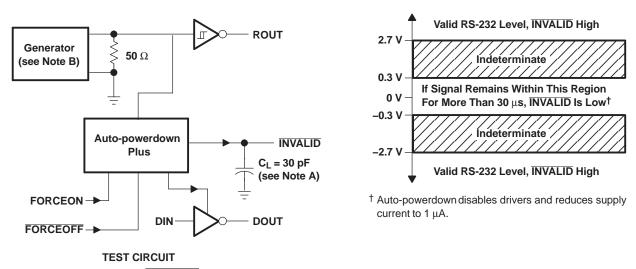


Figure 4. INVALID Propagation Delay Times and Supply Enabling Time

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APPLICATION INFORMATION

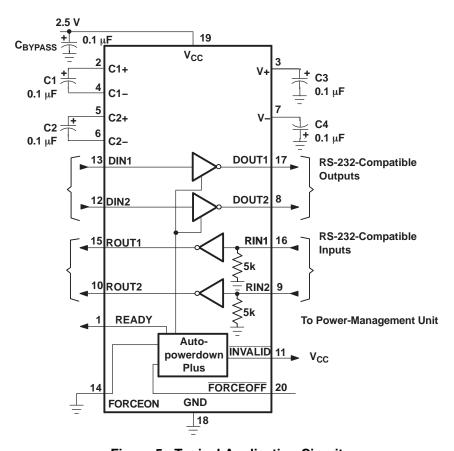


Figure 5. Typical Application Circuit



REVISION HISTORY

CI	Changes from Revision A (April 2010) to Revision B									
•	Updated document to new TI datasheet format - no specification changes.	1								
•	Removed Ordering Information table.	2								
•	Updated TERMINAL FUNCTIONS table to fix inconsistency.	3								

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TRS3318ECDBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV18EC	Samples
TRS3318ECPW	LIFEBUY	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV18EC	
TRS3318ECPWR	LIFEBUY	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	RV18EC	
TRS3318EIDBR	LIFEBUY	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV18EI	
TRS3318EIPW	LIFEBUY	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV18EI	
TRS3318EIPWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RV18EI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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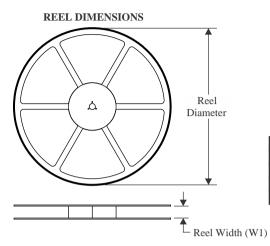
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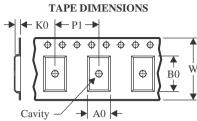
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS3318ECDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRS3318ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TRS3318EIDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRS3318EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS3318ECDBR	SSOP	DB	20	2000	356.0	356.0	35.0
TRS3318ECPWR	TSSOP	PW	20	2000	356.0	356.0	35.0
TRS3318EIDBR	SSOP	DB	20	2000	356.0	356.0	35.0
TRS3318EIPWR	TSSOP	PW	20	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TRS3318ECPW	PW	TSSOP	20	70	530	10.2	3600	3.5
TRS3318EIPW	PW	TSSOP	20	70	530	10.2	3600	3.5





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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